

Electronic Supplementary Information

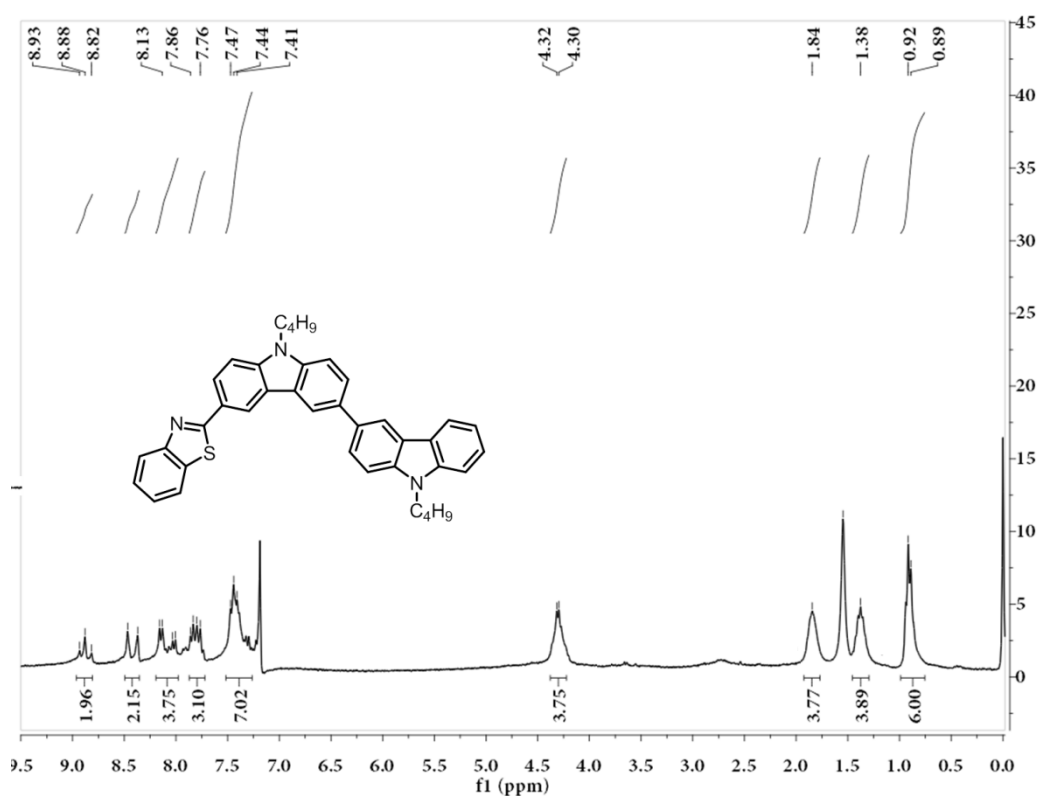
Electronic Effect of Terminal Acceptor Groups on Organic Donor-Acceptor Small-Molecule Induced Different Memory Models

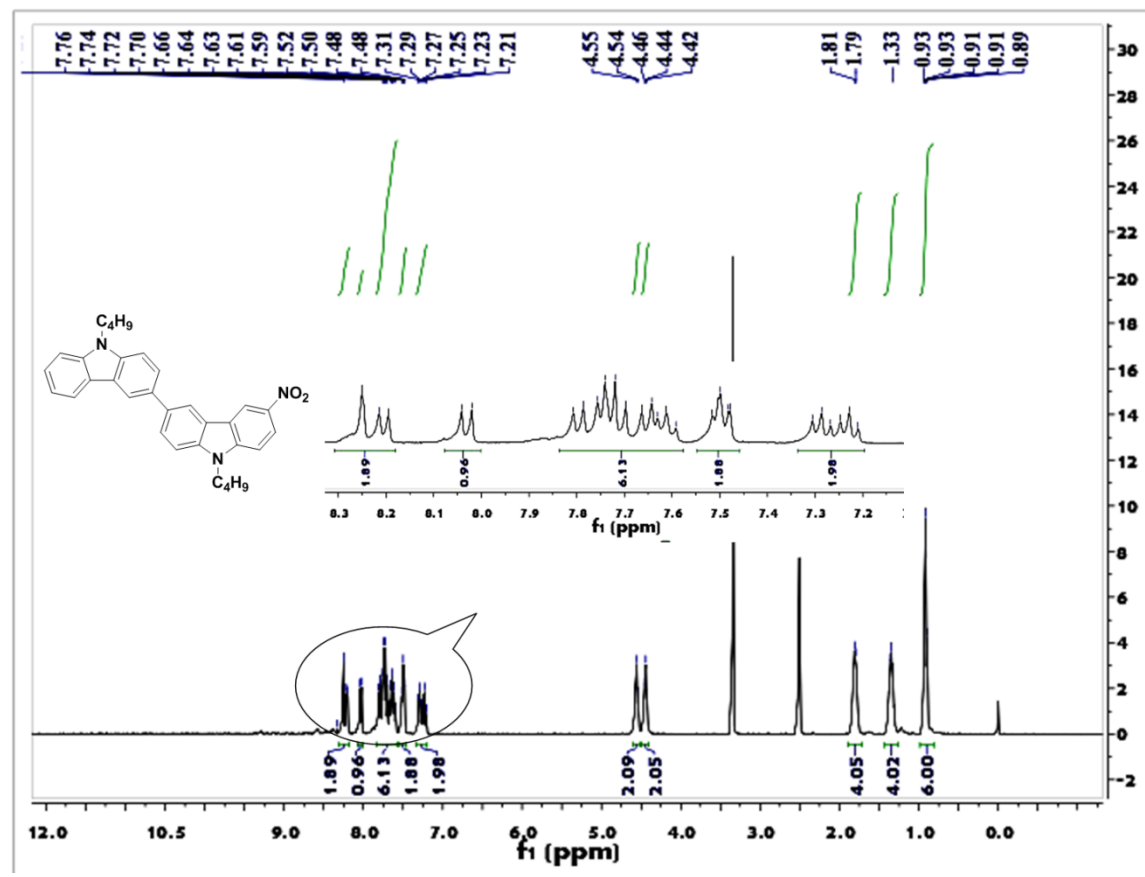
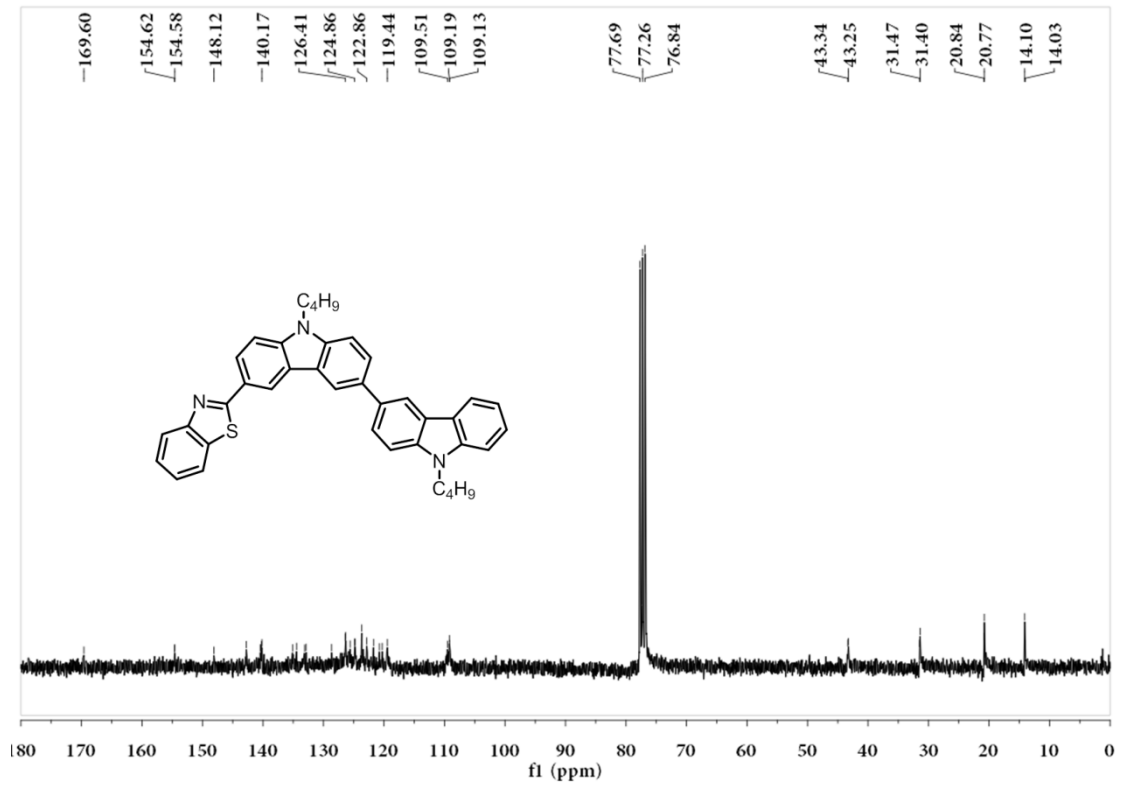
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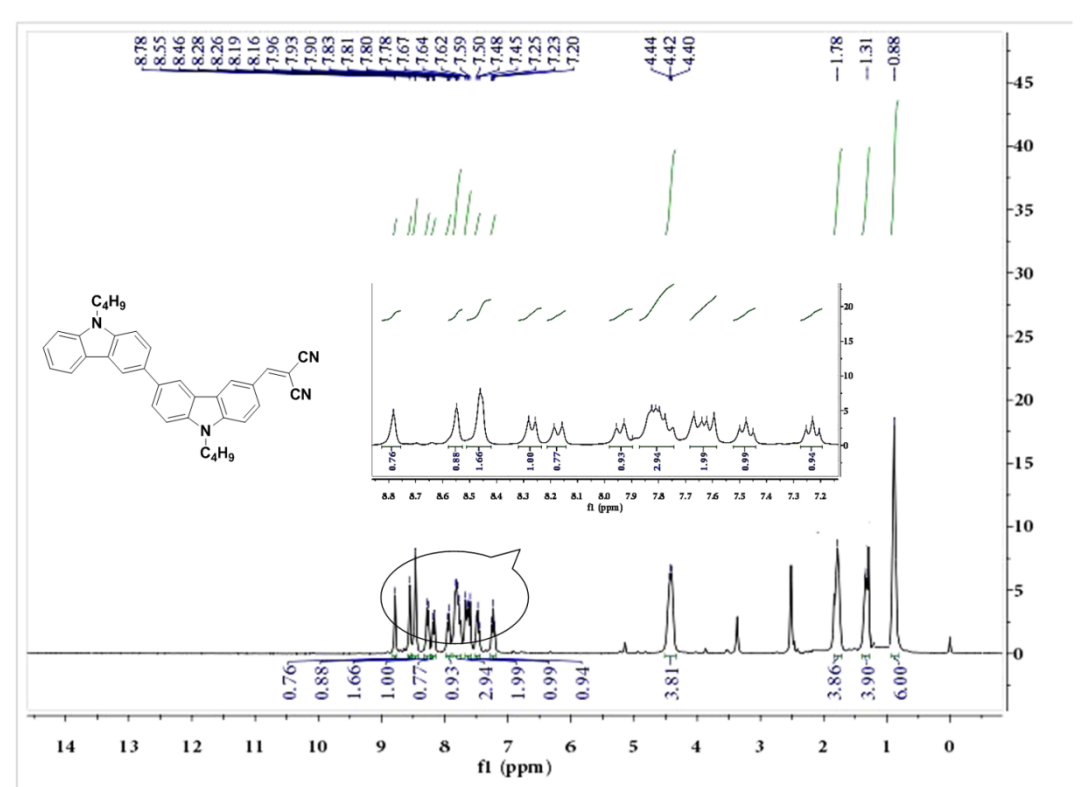
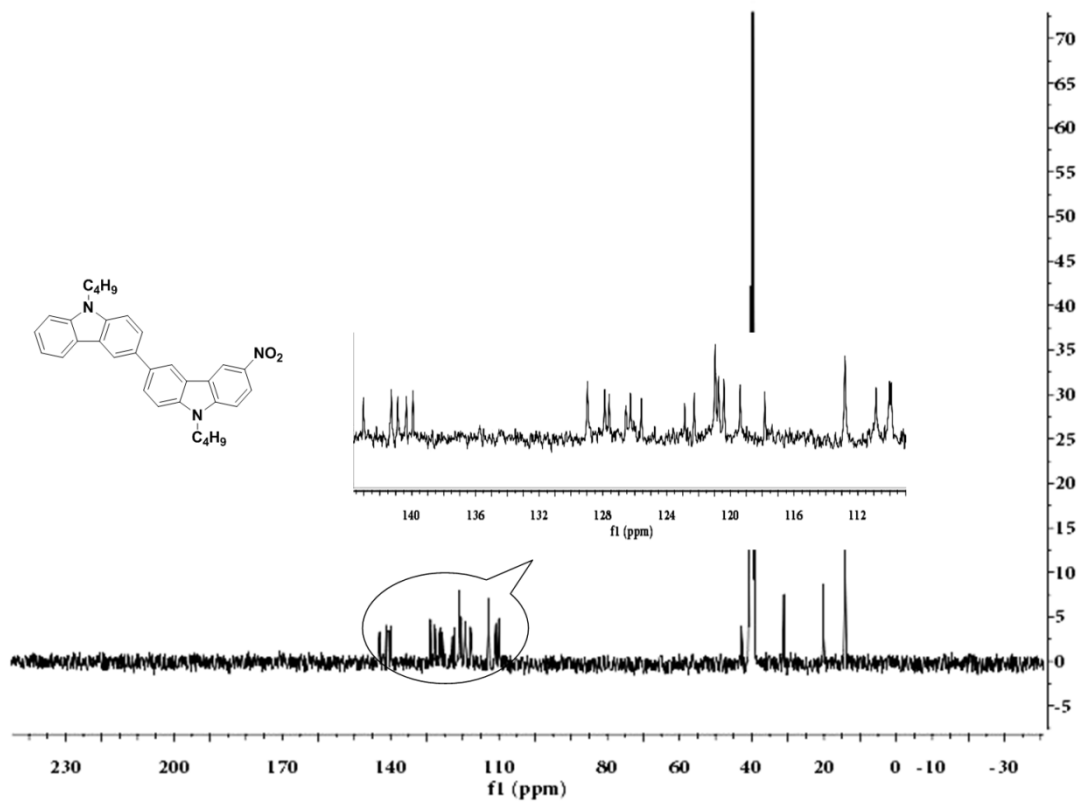
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1. NMR Spectra.







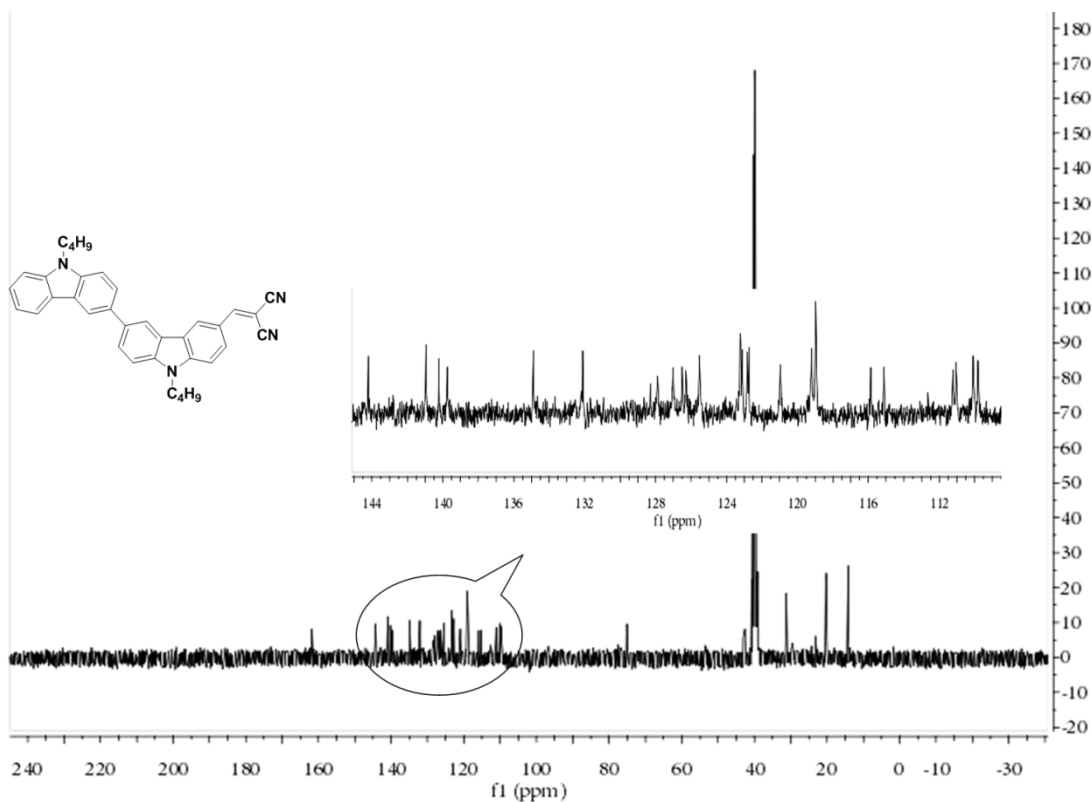


Figure S1 ^1H and ^{13}C NMR spectra of BCz-BT, BCz-NO₂ and BCz-CN

2. Thermo gravimetric analysis (TGA).

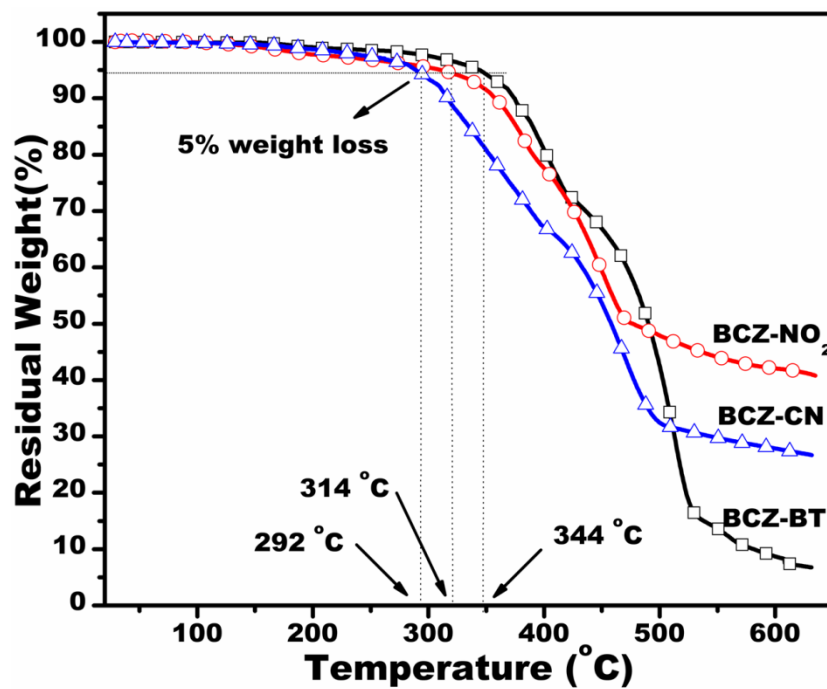


Figure S2 Thermo gravimetric analysis (TGA) curves of three compounds with a heating rate of 20 C min⁻¹ under nitrogen atmosphere.

3. I/t Curves.

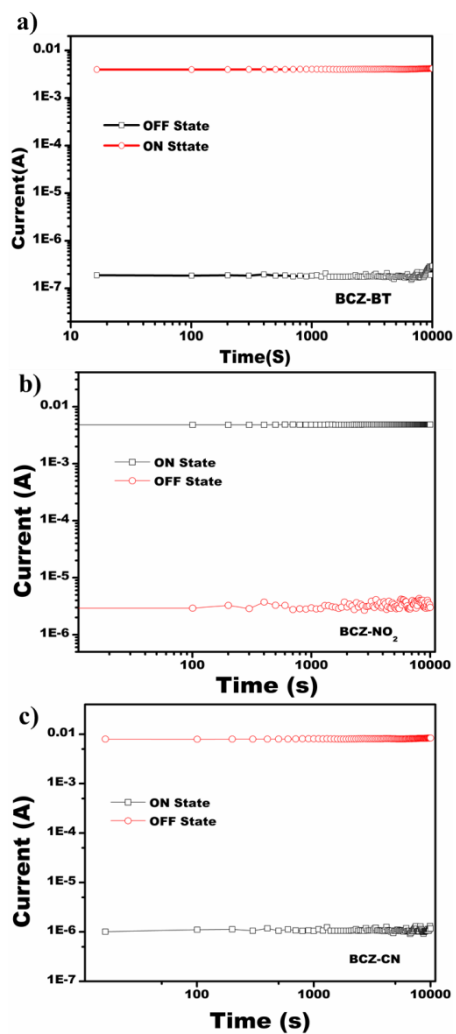


Figure S3 Effect of retention time at 1.0 V on OFF and ON states of BCz-BT, BCz-NO₂ and BCz-CN under a constant stress of 1.0 V.

4. I/V Curves of ITO/BCz/Al.

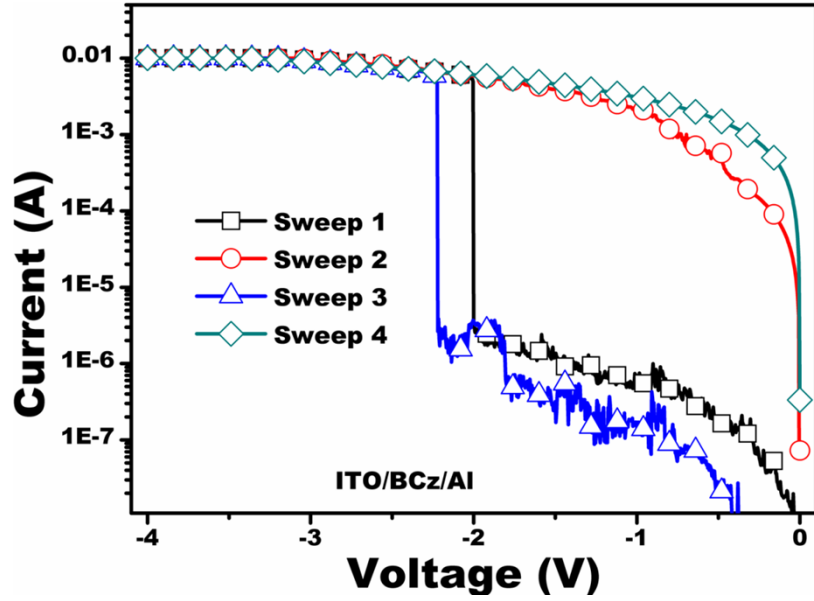


Figure S4 The memory performance of the ITO/BCz/Al device

5. Current models.

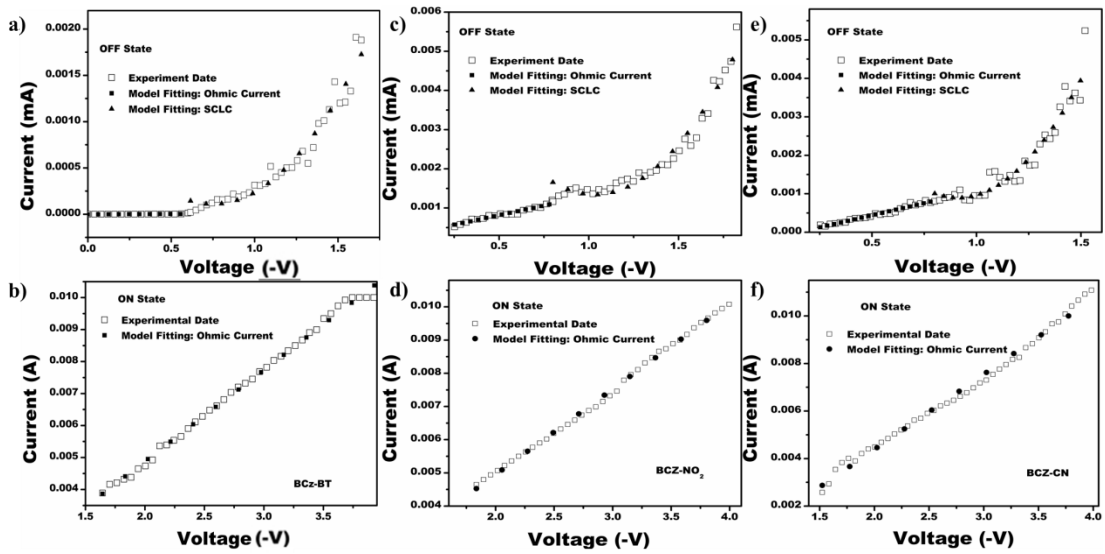


Figure S5 OFF and ON states I-V curves of the experimental and fitted data for the memory devices based on **BCz-BT**, **BCz-NO₂** and **BCZ-CN** of: (a, b, c) The OFF state with the Ohmic current and SCLC model; (b, d, f) The ON state with the ohmic current model.